

## ISL83070E/71E/72E/73E/75E/76E/77E/78E

±15kV ESD Protected, 3.3V, Full Fail-safe, Low Power, High Speed or Slew Rate Limited, RS-485/RS-422 Transceivers

FN6115  
Rev 5.01  
Jul 5, 2022

The ISL8307xE ([ISL83070E](#), [ISL83071E](#), [ISL83072E](#), [ISL83073E](#), [ISL83075E](#), [ISL83076E](#), [ISL83077E](#), [ISL83078E](#)) are BiCMOS 3.3V powered, single transceivers that meet both the RS-485 and RS-422 standards for balanced communication. These devices have very low bus currents (+125µA/-100µA), so they present a true “1/8 unit load” to the RS-485 bus. This allows up to 256 transceivers on the network without violating the RS-485 specification’s 32 unit load maximum, and without using repeaters. For example, in a remote utility meter reading system, individual meter readings are routed to a concentrator via an RS-485 network, so the high allowed node count minimizes the number of repeaters required.

Receiver (Rx) inputs feature a Full Fail-Safe design, which ensures a logic high Rx output if Rx inputs are floating, shorted, or terminated but undriven.

Hot Plug circuitry ensures that the Tx and Rx outputs remain in a high impedance state while the power supply stabilizes.

The ISL83070E through ISL83075E use slew rate limited drivers which reduce EMI, and minimize reflections from improperly terminated transmission lines, or unterminated stubs in multidrop and multipoint applications. Slew rate limited versions also include receiver input filtering to enhance noise immunity in the presence of slow input signals.

The ISL83070E, ISL83071E, ISL83073E, ISL83076E, ISL83077E are configured for full duplex (separate Rx input and Tx output pins) applications. The half duplex versions multiplex the Rx inputs and Tx outputs to allow transceivers with output disable functions in 8 lead packages.

### Features

- Pb-Free (RoHS Compliant)
- RS-485 I/O Pin ESD Protection ..... ±15kV HBM  
- Class 3 ESD Level on all Other Pins ..... >7kV HBM
- Full Fail-safe (Open, Short, Terminated/Floating) Receivers
- Hot Plug - Tx and Rx Outputs Remain Three-state During Power-up (Only Versions with Output Enable Pins)
- True 1/8 Unit Load Allows up to 256 Devices on the Bus
- Single 3.3V Supply
- High Data Rates ..... up to 20Mbps
- Low Quiescent Supply Current ..... 800µA (Max)  
- Ultra Low Shutdown Supply Current ..... 10nA
- -7V to +12V Common Mode Input/Output Voltage Range
- Half and Full Duplex Pinouts
- Three State Rx and Tx Outputs Available
- Current Limiting and Thermal Shutdown for driver Overload Protection
- Tiny MSOP package offering saves 50% board space

### Applications

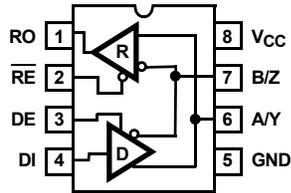
- Automated Utility Meter Reading Systems
- High Node Count Systems
- Field Bus Networks
- Security Camera Networks
- Building Environmental Control/ Lighting Systems
- Industrial/Process Control Networks

TABLE 1. SUMMARY OF FEATURES

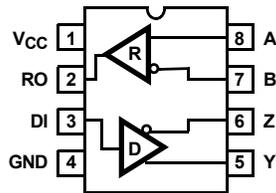
PART NUMBER	HALF/FULL DUPLEX	DATA RATE (Mbps)	SLEW-RATE LIMITED?	HOT PLUG?	#DEVICES ON BUS	RX/TX ENABLE?	QUIESCENT I <sub>CC</sub> (µA)	LOW POWER SHUTDOWN?	PIN COUNT
ISL83070E	FULL	0.25	YES	YES	256	YES	510	YES	14
ISL83071E	FULL	0.25	YES	NO	256	NO	510	NO	8
ISL83072E	HALF	0.25	YES	YES	256	YES	510	YES	8
ISL83073E	FULL	0.5	YES	YES	256	YES	510	YES	14
ISL83075E	HALF	0.5	YES	YES	256	YES	510	YES	8
ISL83076E	FULL	20	NO	YES	256	YES	510	YES	14
ISL83077E	FULL	20	NO	NO	256	NO	510	NO	8
ISL83078E	HALF	20	NO	YES	256	YES	510	YES	8

**Pinouts**

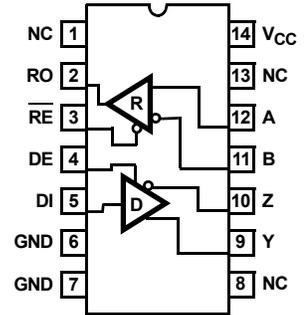
ISL83072E, ISL83075E, ISL83078E  
(8 LD MSOP, SOIC)  
TOP VIEW



ISL83071E, ISL83077E  
(8 LD SOIC)  
TOP VIEW



ISL83070E, ISL83073E, ISL83076E  
(14 LD SOIC)  
TOP VIEW



**Truth Tables**

TRANSMITTING				
INPUTS			OUTPUTS	
RE	DE	DI	Z	Y
X	1	1	0	1
X	1	0	1	0
0	0	X	High-Z	High-Z
1	0	X	High-Z*	High-Z*

NOTE: \*Shutdown Mode (See Note 10), except for ISL83071E/77E

RECEIVING				
INPUTS				OUTPUT
RE	DE Half Duplex	DE Full Duplex	A-B	RO
0	0	X	$\geq -0.05V$	1
0	0	X	$\leq -0.2V$	0
0	0	X	Inputs Open/Shorted	1
1	0	0	X	High-Z*
1	1	1	X	High-Z

NOTE: \*Shutdown Mode (See Note 10), except for ISL83071E/77E

## Pin Descriptions

PIN	FUNCTION
RO	Receiver output: If $A - B \geq -50\text{mV}$ , RO is high; If $A - B \leq -200\text{mV}$ , RO is low; RO = High if A and B are unconnected (floating) or shorted.
$\overline{\text{RE}}$	Receiver output enable. RO is enabled when $\overline{\text{RE}}$ is low; RO is high impedance when $\overline{\text{RE}}$ is high. If the Rx enable function isn't required, connect $\overline{\text{RE}}$ directly to GND or through a $1\text{k}\Omega$ to $3\text{k}\Omega$ resistor to GND.
DE	Driver output enable. The driver outputs, Y and Z, are enabled by bringing DE high, and are high impedance when DE is low. If the Tx enable function isn't required, connect DE to $V_{\text{CC}}$ through a $1\text{k}\Omega$ to $3\text{k}\Omega$ resistor.
DI	Driver input. A low on DI forces output Y low and output Z high. Similarly, a high on DI forces output Y high and output Z low.
GND	Ground connection.
A/Y	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting receiver input and noninverting driver output. Pin is an input if DE = 0; pin is an output if DE = 1.
B/Z	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, Inverting receiver input and inverting driver output. Pin is an input if DE = 0; pin is an output if DE = 1.
A	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting receiver input.
B	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, inverting receiver input.
Y	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting driver output.
Z	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, inverting driver output.
$V_{\text{CC}}$	System power supply input (3.0V to 3.6V).
NC	No Connection.

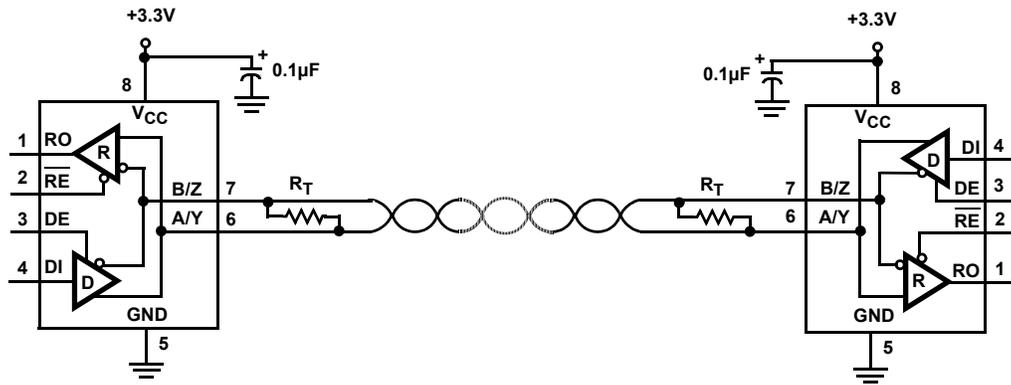
**Ordering Information**

PART NUMBER (Notes 2, 3)	PART MARKING	PACKAGE DESCRIPTION (RoHS Compliant)	PKG. DWG. #	CARRIER TYPE (Note 1)	TEMP. RANGE
ISL83070EIBZA	83070EIBZ	14 Ld SOIC	M14.15	Tube	-40 to 85°C
ISL83070EIBZA-T				Reel, 2.5k	
ISL83071EIBZA	83071 EIBZ	8 Ld SOIC	M8.15	Tube	
ISL83071EIBZA-T				Reel, 2.5k	
ISL83072EIBZA	83072 EIBZ	8 Ld SOIC	M8.15	Tube	
ISL83072EIBZA-T				Reel, 2.5k	
ISL83072EIBZA-T7A				Reel, 250	
ISL83072EIUZA	3072Z	8 Ld MSOP	M8.118	Tube	
ISL83072EIUZA-T				Reel, 2.5k	
ISL83073EIBZA	83073EIBZ	14 Ld SOIC	M14.15	Tube	
ISL83073EIBZA-T				Reel, 2.5k	
ISL83075EIBZA	83075 EIBZ	8 Ld SOIC	M8.15	Tube	
ISL83075EIBZA-T				Reel, 2.5k	
ISL83075EIUZA	3075Z	8 Ld MSOP	M8.118	Tube	
ISL83075EIUZA-T				Reel, 2.5k	
ISL83076EIBZA	83076EIBZ	14 Ld SOIC	M14.15	Tube	
ISL83076EIBZA-T				Reel, 2.5k	
ISL83077EIBZA	83077 EIBZ	8 Ld SOIC	M8.15	Tube	
ISL83077EIBZA-T				Reel, 2.5k	
ISL83078EIBZA	83078 EIBZ	8 Ld SOIC	M8.15	Tube	
ISL83078EIBZA-T				Reel, 2.5k	
ISL83078EIUZA	3078Z	8 Ld MSOP	M8.118	Tube	
ISL83078EIUZA-T				Reel, 2.5k	

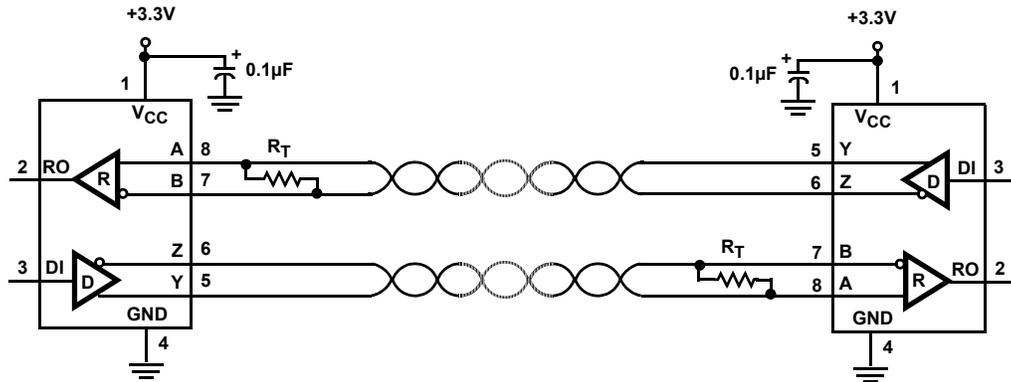
## NOTES:

- See [TB347](#) for details about reel specifications.
- These Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- For Moisture Sensitivity Level (MSL), please see device information page for [ISL83070E](#), [ISL83071E](#), [ISL83072E](#), [ISL83073E](#), [ISL83075E](#), [ISL83076E](#), [ISL83077E](#), [ISL83078E](#). For more information about MSL, see [TB363](#).

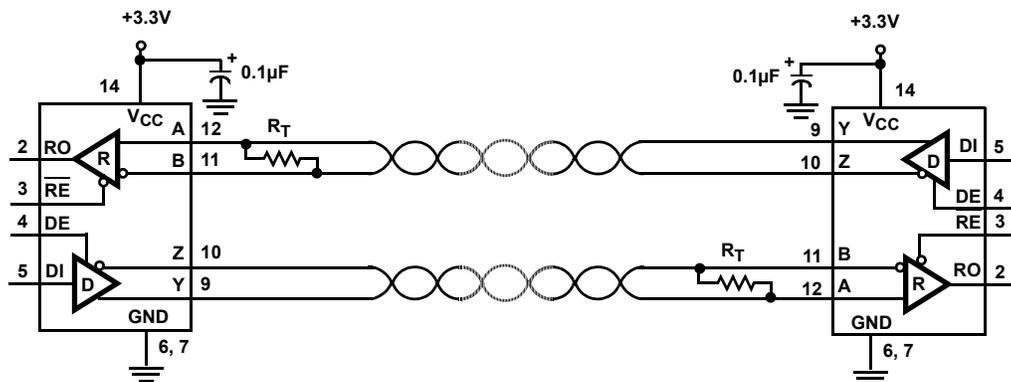
Typical Operating Circuits



ISL83072E, ISL83075E, ISL83078E



ISL83071E, ISL83077E



ISL83070E, ISL83073E, ISL83076E

**Absolute Maximum Ratings**

V<sub>CC</sub> to Ground . . . . . 7V

Input Voltages

DI . . . . . -0.3V to 7V

DE, RE (Note 20) . . . . . -0.3V to 7V

Input/Output Voltages

A, B, Y, Z . . . . . -9V to +13V

RO . . . . . -0.3V to (V<sub>CC</sub> +0.3V)

Short Circuit Duration

Y, Z . . . . . Continuous

ESD Rating . . . . . See Specification Table

**Thermal Information**

Thermal Resistance (Typical, Note 4) θ<sub>JA</sub> (°C/W)

8 Ld SOIC Package . . . . . 105

8 Ld MSOP Package . . . . . 140

14 Ld SOIC Package . . . . . 128

Maximum Junction Temperature (Plastic Package) . . . . . +150°C

Maximum Storage Temperature Range . . . . . -65°C to +150°C

Pb-free reflow profile . . . . . see [TB493](#)

**Operating Conditions**

Temperature Range . . . . . -40°C to +85°C

*CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.*

NOTE:

4. θ<sub>JA</sub> is measured with the component mounted on a high effective thermal conductivity test board in free air. See [TB379](#) for details.

**Electrical Specifications**

Test Conditions: V<sub>CC</sub> = 3.0V to 3.6V; Unless Otherwise Specified. Typicals are at V<sub>CC</sub> = 3.3V, T<sub>A</sub> = +25°C (Note 5).

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 19)	TYP	MAX (Note 19)	UNITS	
<b>DC CHARACTERISTICS</b>								
Driver Differential V <sub>OUT</sub>	V <sub>OD</sub>	R <sub>L</sub> = 100Ω (RS-422) (Figure 1A, Note 16)	Full	2	2.3	-	V	
		R <sub>L</sub> = 54Ω (RS-485) (Figure 1A)	Full	1.5	2	V <sub>CC</sub>	V	
		No Load		-	-	V <sub>CC</sub>		
		R <sub>L</sub> = 60Ω, -7V ≤ V <sub>CM</sub> ≤ 12V (Figure 1B)	Full	1.5	2.2	-	V	
Change in Magnitude of Driver Differential V <sub>OUT</sub> for Complementary Output States	ΔV <sub>OD</sub>	R <sub>L</sub> = 54Ω or 100Ω (Figure 1A)	Full	-	0.01	0.2	V	
Driver Common-Mode V <sub>OUT</sub>	V <sub>OC</sub>	R <sub>L</sub> = 54Ω or 100Ω (Figure 1A)	Full	-	2	3	V	
Change in Magnitude of Driver Common-Mode V <sub>OUT</sub> for Complementary Output States	ΔV <sub>OC</sub>	R <sub>L</sub> = 54Ω or 100Ω (Figure 1A)	Full	-	0.01	0.2	V	
Logic Input High Voltage	V <sub>IH</sub>	DI, DE, RE	Full	2	-	-	V	
Logic Input Low Voltage	V <sub>IL</sub>	DI, DE, RE	Full	-	-	0.8	V	
Logic Input Hysteresis	V <sub>HYS</sub>	DE, RE, (Note 15)	25	-	100	-	mV	
Logic Input Current	I <sub>IN1</sub>	DI = DE = RE = 0V or V <sub>CC</sub> . (Note 18)	Full	-2	-	2	μA	
Input Current (A, B, A/Y, B/Z)	I <sub>IN2</sub>	DE = 0V, V <sub>CC</sub> = 0V or 3.6V	V <sub>IN</sub> = 12V	Full	-	80	125	μA
			V <sub>IN</sub> = -7V	Full	-100	-50	-	μA
Output Leakage Current (Y, Z) (Full Duplex Versions Only, Note 13)	I <sub>IN3</sub>	RE = 0V, DE = 0V, V <sub>CC</sub> = 0V or 3.6V	V <sub>IN</sub> = 12V	Full	-	10	40	μA
			V <sub>IN</sub> = -7V	Full	-40	-10	-	μA
Output Leakage Current (Y, Z) in Shutdown Mode (Full Duplex, Note 13)	I <sub>IN4</sub>	RE = V <sub>CC</sub> , DE = 0V, V <sub>CC</sub> = 0V or 3.6V	V <sub>IN</sub> = 12V	Full	-	10	40	μA
			V <sub>IN</sub> = -7V	Full	-40	-10	-	μA
Driver Short-Circuit Current, V <sub>O</sub> = High or Low	I <sub>OSD1</sub>	DE = V <sub>CC</sub> , -7V ≤ V <sub>Y</sub> or V <sub>Z</sub> ≤ 12V (Note 7)	Full	-	-	±250	mA	
Receiver Differential Threshold Voltage	V <sub>TH</sub>	-7V ≤ V <sub>CM</sub> ≤ 12V	Full	-200	-125	-50	mV	
Receiver Input Hysteresis	ΔV <sub>TH</sub>	V <sub>CM</sub> = 0V	25	-	15	-	mV	

**Electrical Specifications** Test Conditions:  $V_{CC} = 3.0V$  to  $3.6V$ ; Unless Otherwise Specified. Typical values are at  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$  (Note 5). **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 19)	TYP	MAX (Note 19)	UNITS	
Receiver Output High Voltage	$V_{OH}$	$I_O = -4mA$ , $V_{ID} = -50mV$	Full	$V_{CC} - 0.6$	-	-	V	
Receiver Output Low Voltage	$V_{OL}$	$I_O = -4mA$ , $V_{ID} = -200mV$	Full	-	0.17	0.4	V	
Three-State (high impedance) Receiver Output Current (Note 13)	$I_{OZR}$	$0.4V \leq V_O \leq 2.4V$	Full	-1	0.015	1	$\mu A$	
Receiver Input Resistance	$R_{IN}$	$-7V \leq V_{CM} \leq 12V$	Full	96	150	-	k $\Omega$	
Receiver Short-Circuit Current	$I_{OSR}$	$0V \leq V_O \leq V_{CC}$	Full	$\pm 7$	30	$\pm 60$	mA	
Thermal Shutdown Threshold	$T_{SD}$		Full	-	150	-	$^\circ C$	
<b>SUPPLY CURRENT</b>								
No-Load Supply Current (Note 6)	$I_{CC}$	$DI = 0V$ or $V_{CC}$	$\overline{DE} = V_{CC}$ , $\overline{RE} = 0V$ or $V_{CC}$	Full	-	510	800	$\mu A$
			$DE = 0V$ , $\overline{RE} = 0V$	Full	-	480	700	$\mu A$
Shutdown Supply Current (Note 13)	$I_{SHDN}$	$DE = 0V$ , $\overline{RE} = V_{CC}$ , $DI = 0V$ or $V_{CC}$	Full	-	0.01	1	$\mu A$	
<b>ESD PERFORMANCE</b>								
RS-485 Pins (A, Y, B, Z)		Human Body Model (HBM), Pin to GND	25	-	$\pm 15$	-	kV	
All Other Pins		HBM, per MIL-STD-883 Method 3015	25	-	$> \pm 7$	-	kV	
<b>DRIVER SWITCHING CHARACTERISTICS (ISL83070E, ISL83071E, ISL83072E, 250kbps)</b>								
Maximum Data Rate	$f_{MAX}$	$V_{OD} = \pm 1.5V$ , $C_D = 820pF$ (Figure 4, Note 17)	Full	250	800	-	kbps	
Driver Differential Output Delay	$t_{DD}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	250	1100	1500	ns	
Driver Differential Output Skew	$t_{SKEW}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	-	6	100	ns	
Driver Differential Rise or Fall Time	$t_R$ , $t_F$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	350	960	1600	ns	
Driver Enable to Output High	$t_{ZH}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = GND$ (Figure 3), (Notes 8, 13)	Full	-	26	600	ns	
Driver Enable to Output Low	$t_{ZL}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = V_{CC}$ (Figure 3), (Notes 8, 13)	Full	-	200	600	ns	
Driver Disable from Output High	$t_{HZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = GND$ (Figure 3), (Note 13)	Full	-	28	55	ns	
Driver Disable from Output Low	$t_{LZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = V_{CC}$ (Figure 3), (Note 13)	Full	-	30	55	ns	
Time to Shutdown	$t_{SHDN}$	(Notes 10, 13)	Full	50	200	600	ns	
Driver Enable from Shutdown to Output High	$t_{ZH(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = GND$ (Figure 3), (Notes 10, 11, 13)	Full	-	180	700	ns	
Driver Enable from Shutdown to Output Low	$t_{ZL(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = V_{CC}$ (Figure 3), (Notes 10, 11, 13)	Full	-	100	700	ns	
<b>DRIVER SWITCHING CHARACTERISTICS (ISL83073E, ISL83075E, 500kbps)</b>								
Maximum Data Rate	$f_{MAX}$	$V_{OD} = \pm 1.5V$ , $C_D = 820pF$ (Figure 4, Note 17)	Full	500	1600	-	kbps	
Driver Differential Output Delay	$t_{DD}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	180	350	800	ns	
Driver Differential Output Skew	$t_{SKEW}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	-	1	30	ns	
Driver Differential Rise or Fall Time	$t_R$ , $t_F$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	200	380	800	ns	
Driver Enable to Output High	$t_{ZH}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = GND$ (Figure 3), (Notes 8, 13)	Full	-	26	350	ns	
Driver Enable to Output Low	$t_{ZL}$	$R_L = 500\Omega$ , $C_L = 50pF$ , $SW = V_{CC}$ (Figure 3), (Notes 8, 13)	Full	-	100	350	ns	

**Electrical Specifications** Test Conditions:  $V_{CC} = 3.0V$  to  $3.6V$ ; Unless Otherwise Specified. Typical values are at  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$  (Note 5). **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 19)	TYP	MAX (Note 19)	UNITS	
Driver Disable from Output High	$t_{HZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = GND (Figure 3), (Note 13)	Full	-	28	55	ns	
Driver Disable from Output Low	$t_{LZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = $V_{CC}$ (Figure 3), (Note 13)	Full	-	30	55	ns	
Time to Shutdown	$t_{SHDN}$	(Notes 10, 13)	Full	50	200	600	ns	
Driver Enable from Shutdown to Output High	$t_{ZH(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = GND (Figure 3), (Notes 10, 11, 13)	Full	-	180	700	ns	
Driver Enable from Shutdown to Output Low	$t_{ZL(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = $V_{CC}$ (Figure 3), (Notes 10, 11, 13)	Full	-	100	700	ns	
<b>DRIVER SWITCHING CHARACTERISTICS (ISL83076E, ISL83077E, ISL83078E, 20Mbps)</b>								
Maximum Data Rate	$f_{MAX}$	$V_{OD} = \pm 1.5V$ , $C_D = 350pF$ (Figure 4, Note 17)	Full	20	28	-	Mbps	
Driver Differential Output Delay	$t_{DD}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	-	27	40	ns	
Driver Differential Output Skew	$t_{SKEW}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	-	1	3	ns	
Driver Output Skew, Part-to-Part	$\Delta t_{DSKEW}$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2, Note 14)	Full	-	-	11	ns	
Driver Differential Rise or Fall Time	$t_R, t_F$	$R_{DIFF} = 54\Omega$ , $C_D = 50pF$ (Figure 2)	Full	-	9	15	ns	
Driver Enable to Output High	$t_{ZH}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = GND (Figure 3), (Notes 8, 13)	Full	-	17	50	ns	
Driver Enable to Output Low	$t_{ZL}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = $V_{CC}$ (Figure 3), (Notes 8, 13)	Full	-	16	40	ns	
Driver Disable from Output High	$t_{HZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = GND (Figure 3), (Note 13)	Full	-	25	40	ns	
Driver Disable from Output Low	$t_{LZ}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = $V_{CC}$ (Figure 3), (Note 13)	Full	-	28	50	ns	
Time to Shutdown	$t_{SHDN}$	(Notes 10, 13)	Full	50	200	600	ns	
Driver Enable from Shutdown to Output High	$t_{ZH(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = GND (Figure 3), (Notes 10, 11, 13)	Full	-	180	700	ns	
Driver Enable from Shutdown to Output Low	$t_{ZL(SHDN)}$	$R_L = 500\Omega$ , $C_L = 50pF$ , SW = $V_{CC}$ (Figure 3), (Notes 10, 11, 13)	Full	-	90	700	ns	
<b>RECEIVER SWITCHING CHARACTERISTICS (All Versions)</b>								
Maximum Data Rate	$f_{MAX}$	$V_{ID} = \pm 1.5V$ (Note 17)	ISL83070E-75E	Full	12	20	-	Mbps
			ISL83076E-78E	Full	20	35	-	Mbps
Receiver Input to Output Delay	$t_{PLH}, t_{PHL}$	(Figure 5)	ISL83070E-75E	Full	25	70	120	ns
			ISL83076E-78E	Full	25	33	60	ns
Receiver Skew   $t_{PLH} - t_{PHL}$	$t_{SKD}$	(Figure 5)	Full	-	1.5	4	ns	
Receiver Skew, Part-to-Part	$\Delta t_{RSKEW}$	(Figure 5, Note 14)	Full	-	-	15	ns	
Receiver Enable to Output High	$t_{ZH}$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = GND (Figure 6), (Notes 9, 13)	ISL83070E-75E	Full	5	15	20	ns
			ISL83076E-78E	Full	5	11	17	ns
Receiver Enable to Output Low	$t_{ZL}$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = $V_{CC}$ (Figure 6), (Notes 9, 13)	ISL83070E-75E	Full	5	15	20	ns
			ISL83076E-78E	Full	5	11	17	ns
Receiver Disable from Output High	$t_{HZ}$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = GND (Figure 6), (Note 13)	ISL83070E-75E	Full	5	12	20	ns
			ISL83076E-78E	Full	4	7	15	ns

**Electrical Specifications** Test Conditions:  $V_{CC} = 3.0V$  to  $3.6V$ ; Unless Otherwise Specified. Typicals are at  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$  (Note 5). **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 19)	TYP	MAX (Note 19)	UNITS	
Receiver Disable from Output Low	$t_{LZ}$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = $V_{CC}$ (Figure 6), (Note 13)	ISL83070E-75E	Full	5	13	20	ns
			ISL83076E-78E	Full	4	7	15	ns
Time to Shutdown	$t_{SHDN}$	(Notes 10, 13)	Full	50	180	600	ns	
Receiver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = GND (Figure 6), (Notes 10, 12, 13)	Full	-	240	500	ns	
Receiver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$R_L = 1k\Omega$ , $C_L = 15pF$ , SW = $V_{CC}$ (Figure 6), (Notes 10, 12, 13)	Full	-	240	500	ns	

NOTES:

- All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified.
- Supply current specification is valid for loaded drivers when  $DE = 0V$ .
- Applies to peak current. See "Typical Performance Curves" for more information.
- When testing devices with the shutdown feature, keep  $\overline{RE} = 0$  to prevent the device from entering SHDN.
- When testing devices with the shutdown feature, the  $\overline{RE}$  signal high time must be short enough (typically  $<100ns$ ) to prevent the device from entering SHDN.
- Versions with a shutdown feature are put into shutdown by bringing  $\overline{RE}$  high and DE low. If the inputs are in this state for less than 50ns, the parts are guaranteed not to enter shutdown. If the inputs are in this state for at least 600ns, the parts are guaranteed to have entered shutdown. See "Low Power Shutdown Mode" on page 12.
- Keep  $\overline{RE} = V_{CC}$ , and set the DE signal low time  $>600ns$  to ensure that the device enters SHDN.
- Set the  $\overline{RE}$  signal high time  $>600ns$  to ensure that the device enters SHDN.
- Does not apply to the ISL83071E and ISL83077E.
- $\Delta t_{SKEW}$  is the magnitude of the difference in propagation delays of the specified terminals of two units tested with identical test conditions ( $V_{CC}$ , temperature, etc.). Only applies to the ISL83076E - 78E.
- ISL83070E - ISL83075E only.
- $V_{CC} \geq 3.15V$
- Limits established by characterization and are not production tested.
- If the Tx or Rx enable function isn't needed, connect the enable pin to the appropriate supply (see "Pin Descriptions" table) through a 1kΩ to 3kΩ resistor.
- Parts are 100% tested at  $+25^\circ C$ . Full temperature limits are guaranteed by bench and tester characterization.
- If the DE or  $\overline{RE}$  input voltage exceeds the  $V_{CC}$  voltage by more than 500mV, then current will flow into the logic pin. The current is limited by a 340Ω resistor (so  $\approx 13mA$  with  $V_{IN} = 5V$  and  $V_{CC} = 0V$ ) so no damage will occur if  $V_{CC} \leq V_{IN} \leq 7V$  for short periods of time.

**Test Circuits and Waveforms**

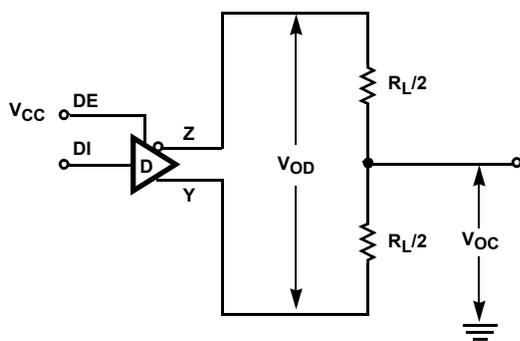


FIGURE 1A.  $V_{OD}$  AND  $V_{OC}$

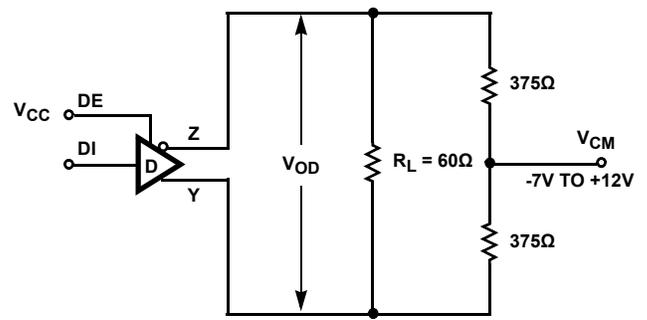


FIGURE 1B.  $V_{OD}$  WITH COMMON MODE LOAD

FIGURE 1. DC DRIVER TEST CIRCUITS

**Test Circuits and Waveforms** (Continued)

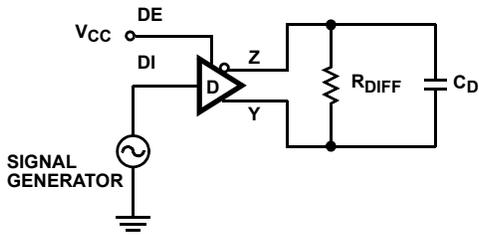


FIGURE 2A. TEST CIRCUIT

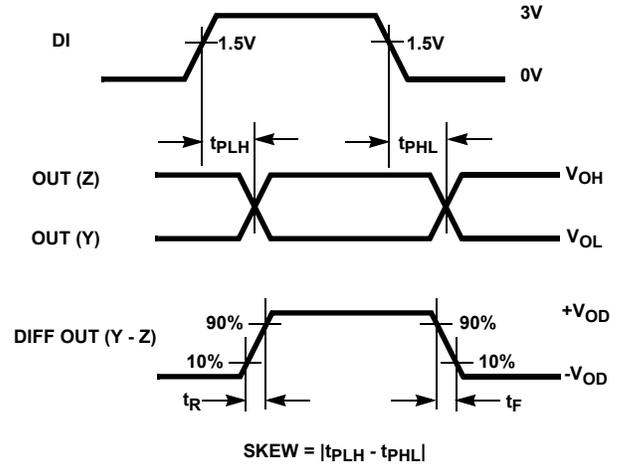
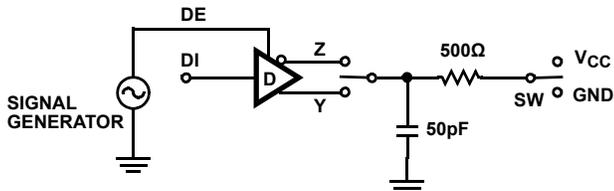


FIGURE 2B. MEASUREMENT POINTS

FIGURE 2. DRIVER PROPAGATION DELAY AND DIFFERENTIAL TRANSITION TIMES



PARAMETER	OUTPUT	RE	DI	SW
$t_{HZ}$	Y/Z	X	1/0	GND
$t_{LZ}$	Y/Z	X	0/1	$V_{CC}$
$t_{ZH}$	Y/Z	0 (Note 8)	1/0	GND
$t_{ZL}$	Y/Z	0 (Note 8)	0/1	$V_{CC}$
$t_{ZH(SHDN)}$	Y/Z	1 (Note 11)	1/0	GND
$t_{ZL(SHDN)}$	Y/Z	1 (Note 11)	0/1	$V_{CC}$

FIGURE 3A. TEST CIRCUIT

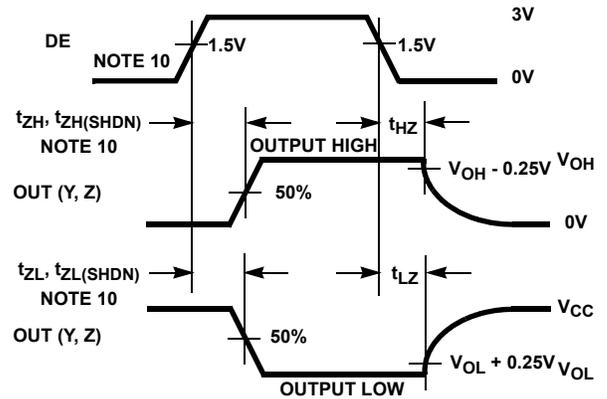


FIGURE 3B. MEASUREMENT POINTS

FIGURE 3. DRIVER ENABLE AND DISABLE TIMES (EXCEPT ISL83071E, ISL83077E)

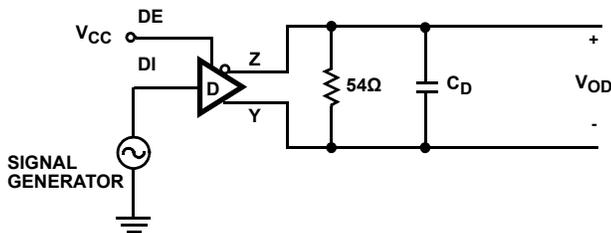


FIGURE 4A. TEST CIRCUIT

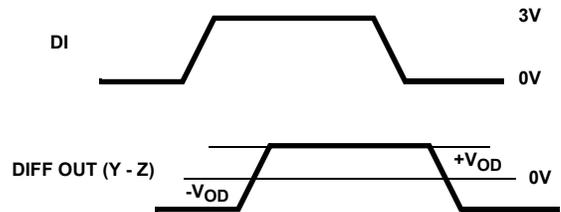


FIGURE 4B. MEASUREMENT POINTS

FIGURE 4. DRIVER DATA RATE

**Test Circuits and Waveforms** (Continued)

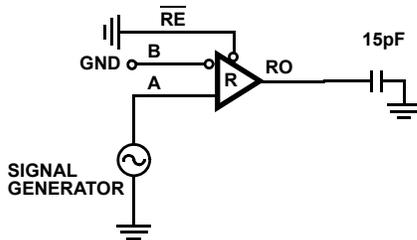


FIGURE 5A. TEST CIRCUIT

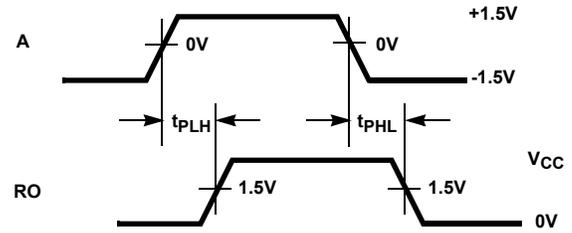
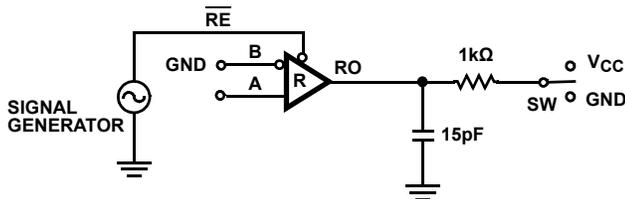


FIGURE 5B. MEASUREMENT POINTS

FIGURE 5. RECEIVER PROPAGATION DELAY



PARAMETER	DE	A	SW
$t_{HZ}$	X	+1.5V	GND
$t_{LZ}$	X	-1.5V	$V_{CC}$
$t_{ZH}$ (Note 9)	0	+1.5V	GND
$t_{ZL}$ (Note 9)	0	-1.5V	$V_{CC}$
$t_{ZH}(SHDN)$ (Note 12)	0	+1.5V	GND
$t_{ZL}(SHDN)$ (Note 12)	0	-1.5V	$V_{CC}$

FIGURE 6A. TEST CIRCUIT

FIGURE 6. RECEIVER ENABLE AND DISABLE TIMES (EXCEPT ISL83071E, ISL83077E)

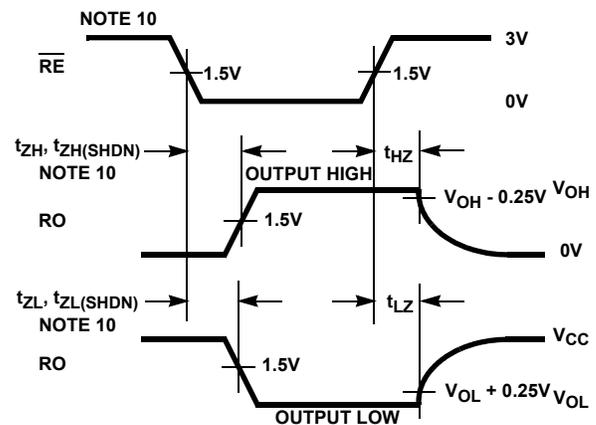


FIGURE 6B. MEASUREMENT POINTS

**Application Information**

RS-485 and RS-422 are differential (balanced) data transmission standards for use in long haul or noisy environments. RS-422 is a subset of RS-485, so RS-485 transceivers are also RS-422 compliant. RS-422 is a point-to-multipoint (multidrop) standard, which allows only one driver and up to 10 (assuming one unit load devices) receivers on each bus. RS-485 is a true multipoint standard, which allows up to 32 one unit load devices (any combination of drivers and receivers) on each bus. To allow for multipoint operation, the RS-485 spec requires that drivers must handle bus contention without sustaining any damage.

Another important advantage of RS-485 is the extended common mode range (CMR), which specifies that the driver outputs and receiver inputs withstand signals that range from +12V to -7V. RS-422 and RS-485 are intended for runs as long as 4000', so the wide CMR is necessary to handle ground potential differences, as well as voltages induced in the cable by external fields.

**Receiver Features**

These devices utilize a differential input receiver for maximum noise immunity and common mode rejection. Input sensitivity is better than  $\pm 200\text{mV}$ , as required by the RS-422 and RS-485 specifications.

Receiver input resistance of  $96\text{k}\Omega$  surpasses the RS-422 spec of  $4\text{k}\Omega$ , and is eight times the RS-485 "Unit Load (UL)" requirement of  $12\text{k}\Omega$  minimum. Thus, these products are known as "one-eighth UL" transceivers, and there can be up to 256 of these devices on a network while still complying with the RS-485 loading spec.

Receiver inputs function with common mode voltages as great as +9V/-7V outside the power supplies (i.e., +12V and -7V), making them ideal for long networks where induced voltages, and ground potential differences, are realistic concerns.

All the receivers include a "full fail-safe" function that guarantees a high level receiver output if the receiver inputs are unconnected (floating) or shorted. Fail-safe with shorted inputs is achieved by setting the Rx upper switching point to -50mV, thereby ensuring that the Rx sees 0V differential as a high input level.

Receivers easily meet the data rates supported by the corresponding driver, and all receiver outputs (except on the ISL83071E and ISL83077E) are tri-statable via the active low  $\overline{RE}$  input.

### Driver Features

The RS-485, RS-422 driver is a differential output device that delivers at least 1.5V across a 54 $\Omega$  load (RS-485), and at least 2V across a 100 $\Omega$  load (RS-422). The drivers feature low propagation delay skew to maximize bit width, and to minimize EMI.

All drivers are tri-statable via the active high DE input, except on the ISL83071E and ISL83077E.

The 250kbps and 500kbps driver outputs are slew rate limited to minimize EMI, and to reduce reflections in unterminated or improperly terminated networks. Outputs of the ISL83076E through ISL83078E drivers are not limited, so faster output transition times allow data rates of at least 20Mbps.

### Hot Plug Function

When a piece of equipment powers up, there is a period of time where the processor or ASIC driving the RS-485 control lines (DE,  $\overline{RE}$ ) is unable to ensure that the RS-485 Tx and Rx outputs are kept disabled. If the equipment is connected to the bus, a driver activating prematurely during power up may crash the bus. To avoid this scenario, the ISL8307XE versions with output enable pins incorporate a "Hot Plug" function. During power up, circuitry monitoring  $V_{CC}$  ensures that the Tx and Rx outputs remain disabled for a period of time, regardless of the state of DE and  $\overline{RE}$ . This gives the processor/ASIC a chance to stabilize and drive the RS-485 control lines to the proper states.

### ESD Protection

All pins on these devices include class 3 (>7kV) Human Body Model (HBM) ESD protection structures, but the RS-485 pins (driver outputs and receiver inputs) incorporate advanced structures allowing them to survive ESD events in excess of  $\pm 15$ kV HBM. The RS-485 pins are particularly vulnerable to ESD damage because they typically connect to an exposed port on the exterior of the finished product. Simply touching the port pins, or connecting a cable, can cause an ESD event that might destroy unprotected ICs. These new ESD structures protect the device whether or not it is powered up, protect without allowing any latchup mechanism to activate, and without degrading the RS-485 common mode range of -7V to +12V. This built-in ESD protection eliminates the need for board level protection structures (e.g., transient suppression diodes), and the associated, undesirable capacitive load they present.

### Data Rate, Cables, and Terminations

RS-485, RS-422 are intended for network lengths up to 4000', but the maximum system data rate decreases as the transmission length increases. Devices operating at 20Mbps are limited to lengths less than 100', while the 250kbps

versions can operate at full data rates with lengths of several thousand feet.

Twisted pair is the cable of choice for RS-485, RS-422 networks. Twisted pair cables tend to pick up noise and other electromagnetically induced voltages as common mode signals, which are effectively rejected by the differential receivers in these ICs.

Proper termination is imperative, when using the 20Mbps devices, to minimize reflections. Short networks using the 250kbps versions need not be terminated, but, terminations are recommended unless power dissipation is an overriding concern.

In point-to-point, or point-to-multipoint (single driver on bus) networks, the main cable should be terminated in its characteristic impedance (typically 120 $\Omega$ ) at the end farthest from the driver. In multi-receiver applications, stubs connecting receivers to the main cable should be kept as short as possible. Multipoint (multi-driver) systems require that the main cable be terminated in its characteristic impedance at both ends. Stubs connecting a transceiver to the main cable should be kept as short as possible.

### Built-In Driver Overload Protection

As stated previously, the RS-485 spec requires that drivers survive worst case bus contentions undamaged. These devices meet this requirement via driver output short circuit current limits, and on-chip thermal shutdown circuitry.

The driver output stages incorporate short circuit current limiting circuitry which ensures that the output current never exceeds the RS-485 spec, even at the common mode voltage range extremes. Additionally, these devices utilize a foldback circuit which reduces the short circuit current, and thus the power dissipation, whenever the contending voltage exceeds either supply.

In the event of a major short circuit condition, devices also include a thermal shutdown feature that disables the drivers whenever the die temperature becomes excessive. This eliminates the power dissipation, allowing the die to cool. The drivers automatically re-enable after the die temperature drops about +15°. If the contention persists, the thermal shutdown/re-enable cycle repeats until the fault is cleared. Receivers stay operational during thermal shutdown.

### Low Power Shutdown Mode

These CMOS transceivers all use a fraction of the power required by their bipolar counterparts, but some also include a shutdown feature that reduces the already low quiescent  $I_{CC}$  to a 10nA trickle. These devices enter shutdown whenever the receiver and driver are **simultaneously** disabled ( $\overline{RE} = V_{CC}$  and DE = GND) for a period of at least 600ns. Disabling both the driver and the receiver for less than 50ns guarantees that the transceiver will not enter shutdown.

Note that receiver and driver enable times increase when the transceiver enables from shutdown. Refer to Notes 8 through 12, at the end of the "Electrical Specifications" table on page 9 for more information.

**Typical Performance Curves**  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$ ; Unless Otherwise Specified

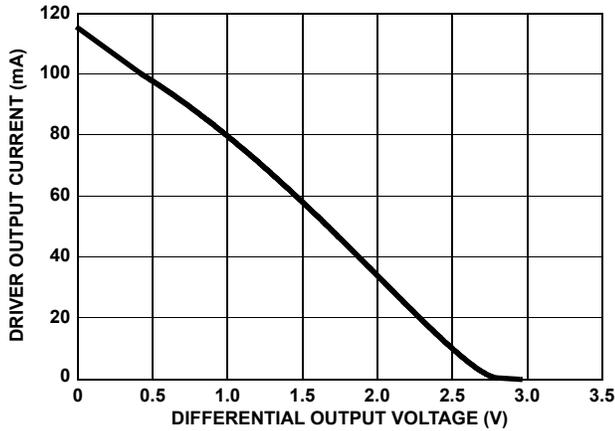


FIGURE 7. DRIVER OUTPUT CURRENT vs DIFFERENTIAL OUTPUT VOLTAGE

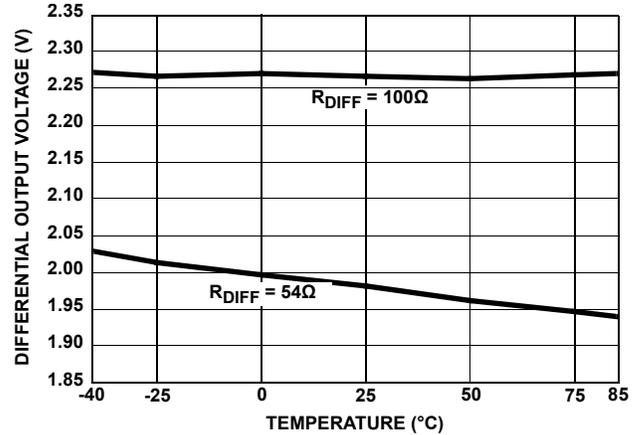


FIGURE 8. DRIVER DIFFERENTIAL OUTPUT VOLTAGE vs TEMPERATURE

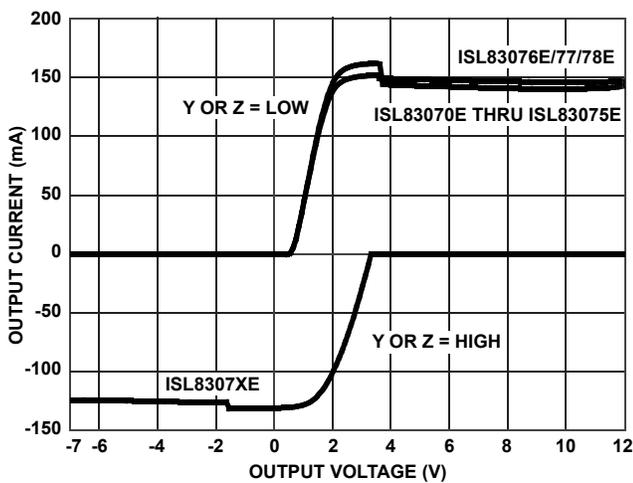


FIGURE 9. DRIVER OUTPUT CURRENT vs SHORT CIRCUIT VOLTAGE

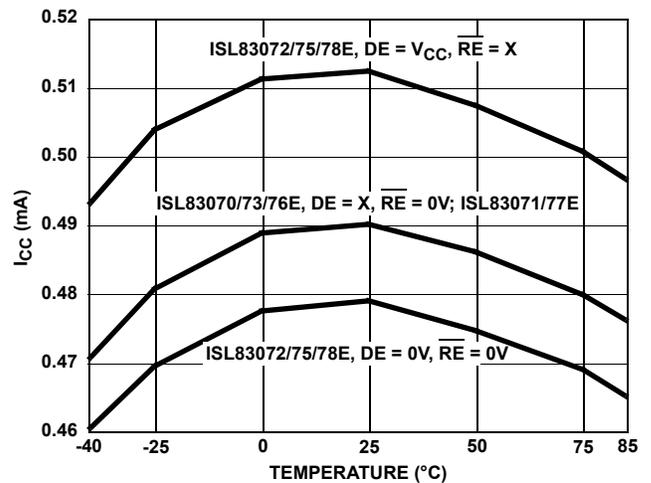


FIGURE 10. SUPPLY CURRENT vs TEMPERATURE

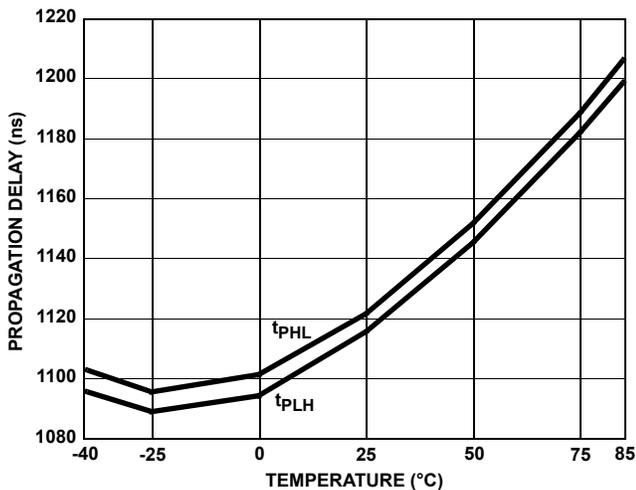


FIGURE 11. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83070E, ISL83071E, ISL83072E)

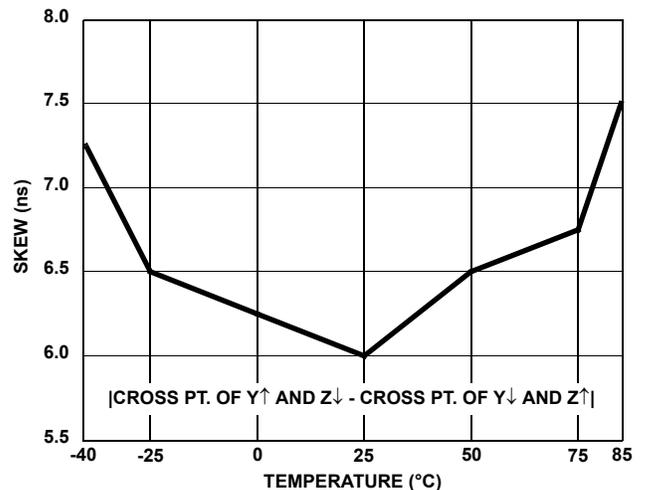


FIGURE 12. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83070E, ISL83071E, ISL83072E)

**Typical Performance Curves**  $V_{CC} = 3.3V, T_A = +25^{\circ}C$ ; Unless Otherwise Specified (Continued)

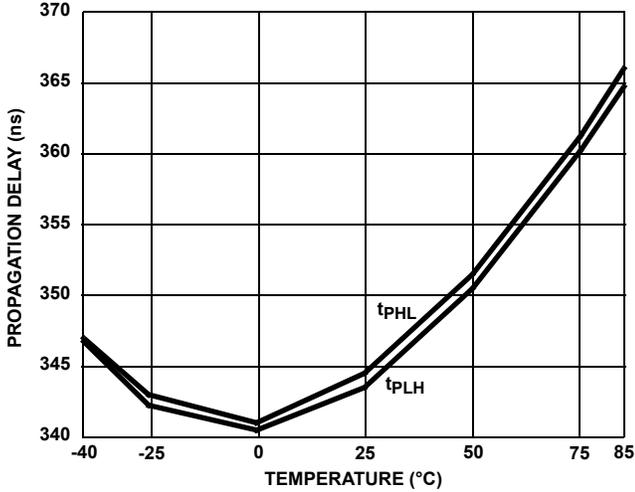


FIGURE 13. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83073E, ISL83075E)

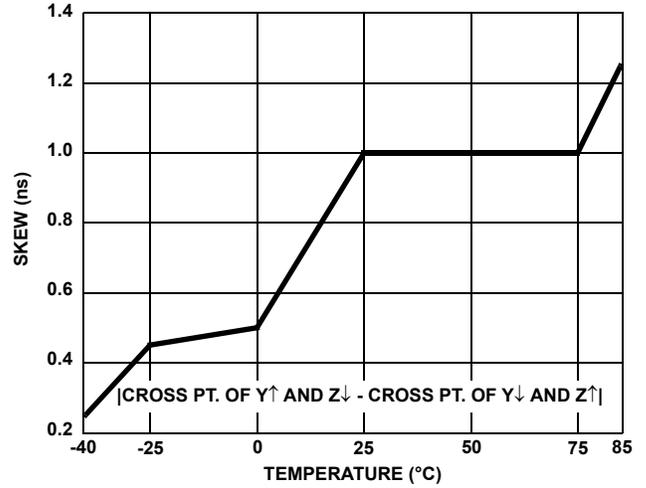


FIGURE 14. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83073E, ISL83075E)

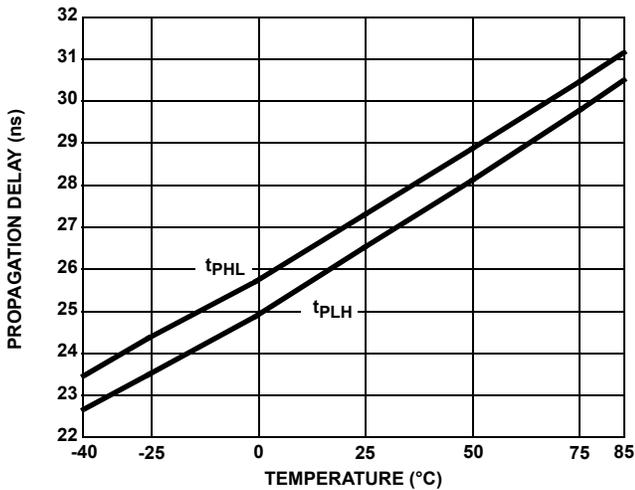


FIGURE 15. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83076E, ISL83077E, ISL83078E)

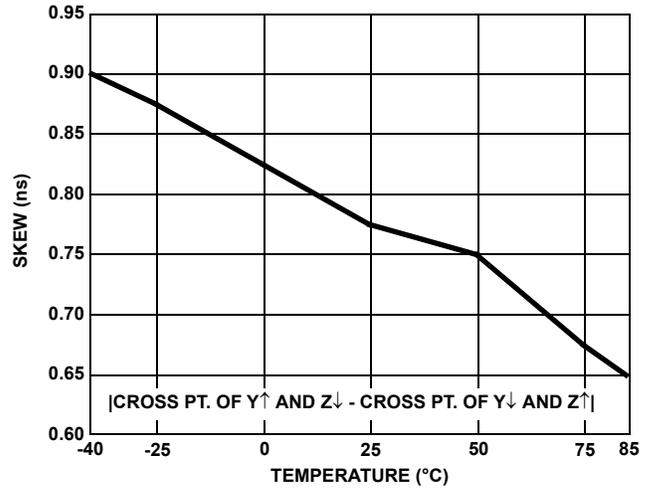


FIGURE 16. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83076E, ISL83077E, ISL83078E)

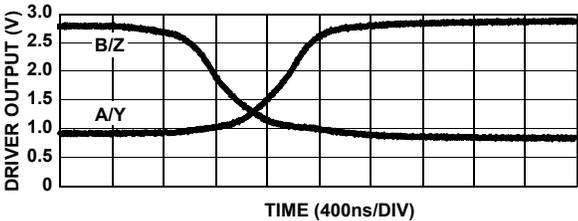
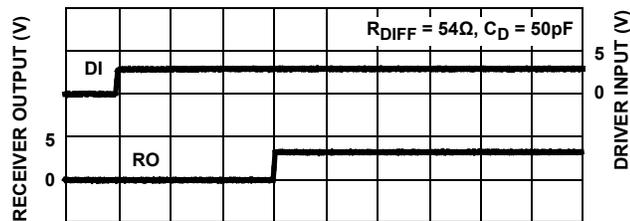


FIGURE 17. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83070E, ISL83071E, ISL83072E)

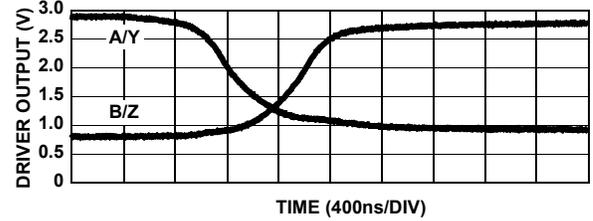
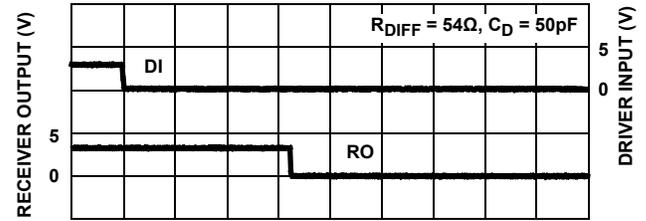


FIGURE 18. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83070E, ISL83071E, ISL83072E)

**Typical Performance Curves**  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$ ; Unless Otherwise Specified (Continued)

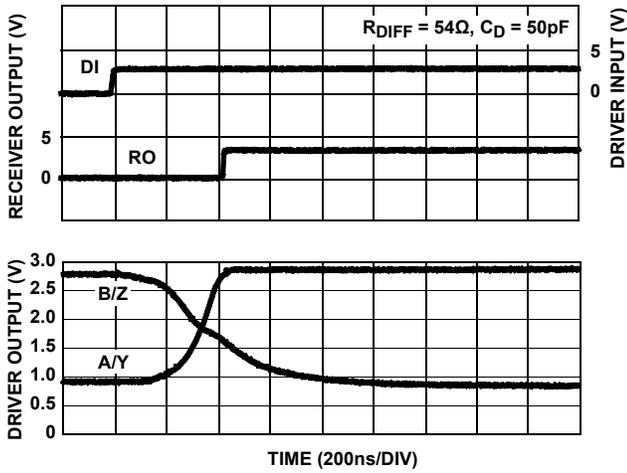


FIGURE 19. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83073E, ISL83075E)

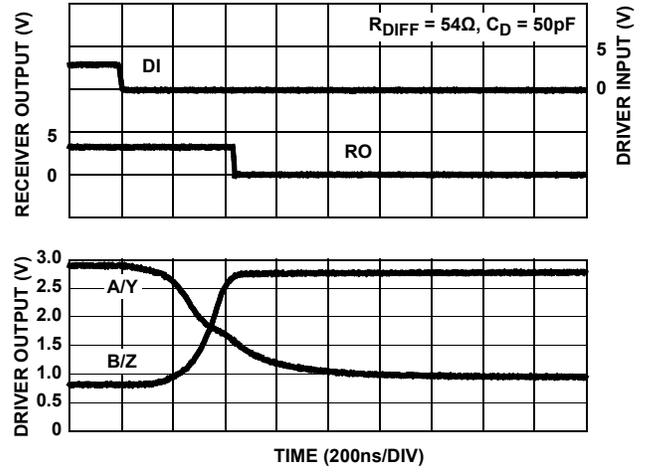


FIGURE 20. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83073E, ISL83075E)

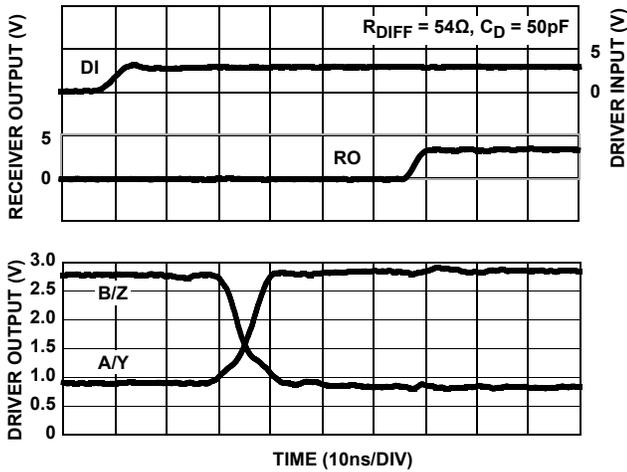


FIGURE 21. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83076E, ISL83077E, ISL83078E)

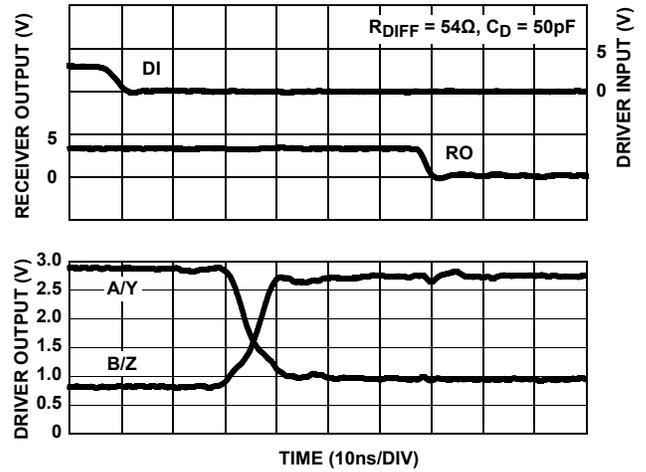


FIGURE 22. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83076E, ISL83077E, ISL83078E)

**Typical Performance Curves**  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$ ; Unless Otherwise Specified (Continued)

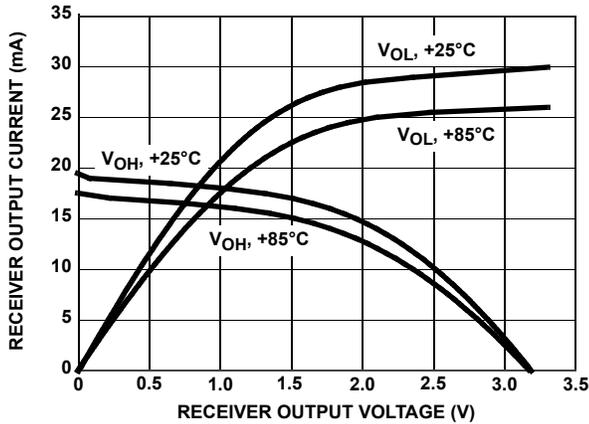


FIGURE 23. RECEIVER OUTPUT CURRENT vs RECEIVER OUTPUT VOLTAGE

**Die Characteristics**

**SUBSTRATE POTENTIAL (POWERED UP):**

GND

**TRANSISTOR COUNT:**

535

**PROCESS:**

Si Gate BiCMOS

**Revision History**

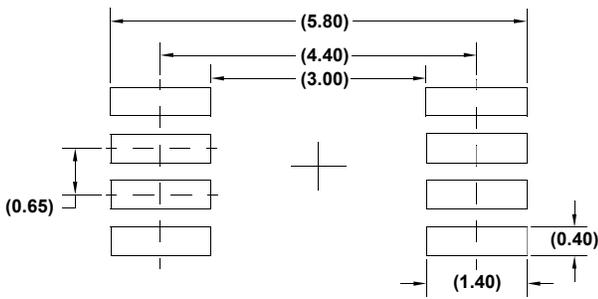
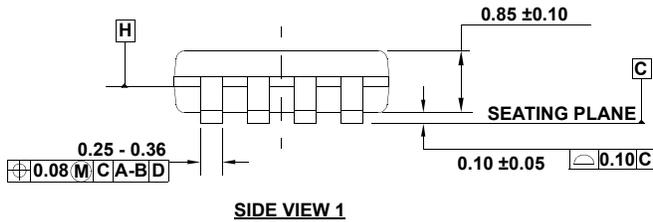
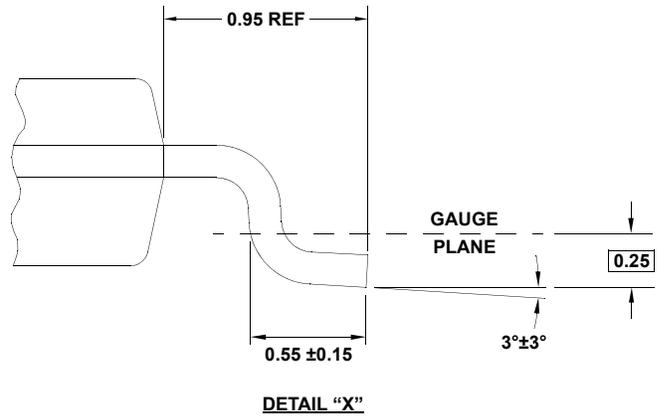
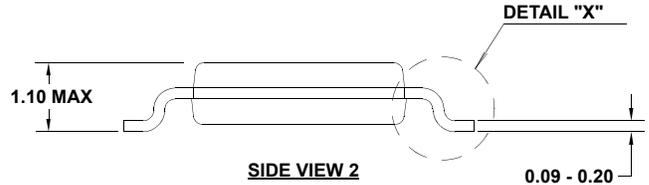
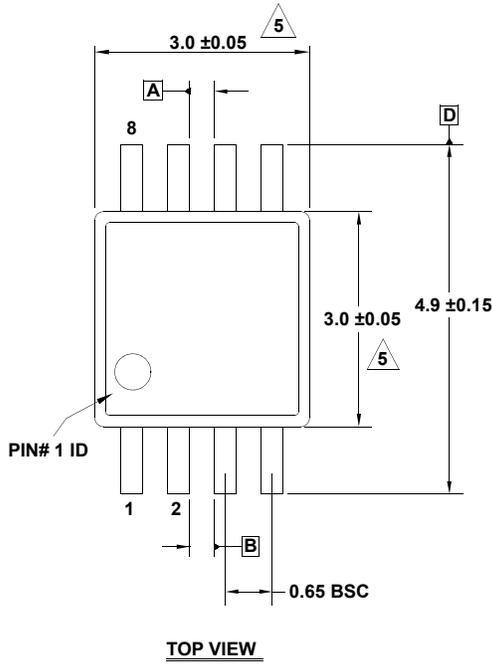
The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
Jul 5, 2022	5.01	Updated unit error on page 1 in the first paragraph. Updated Ordering Information table format. Updated M8.118 POD to the latest revision, changes are as follows: -Corrected typo in the side view 1 updating package thickness tolerance from $\pm 0.10$ to $\pm 0.10$ . Updated M14.15 POD to the latest revision, changes are as follows: -In Side View B and Detail A: Added lead length dimension (1.27 – 0.40) Changed angle of the lead to 0-8 degrees. Updated M8.15 POD to the latest revision, changes are as follows: -Added the coplanarity spec into the drawing. Added Revision History

## Package Outline Drawings

For the most recent package outline drawing, see M8.118.

M8.118  
 8 Lead Mini Small Outline Plastic Package  
 Rev 5, 5/2021

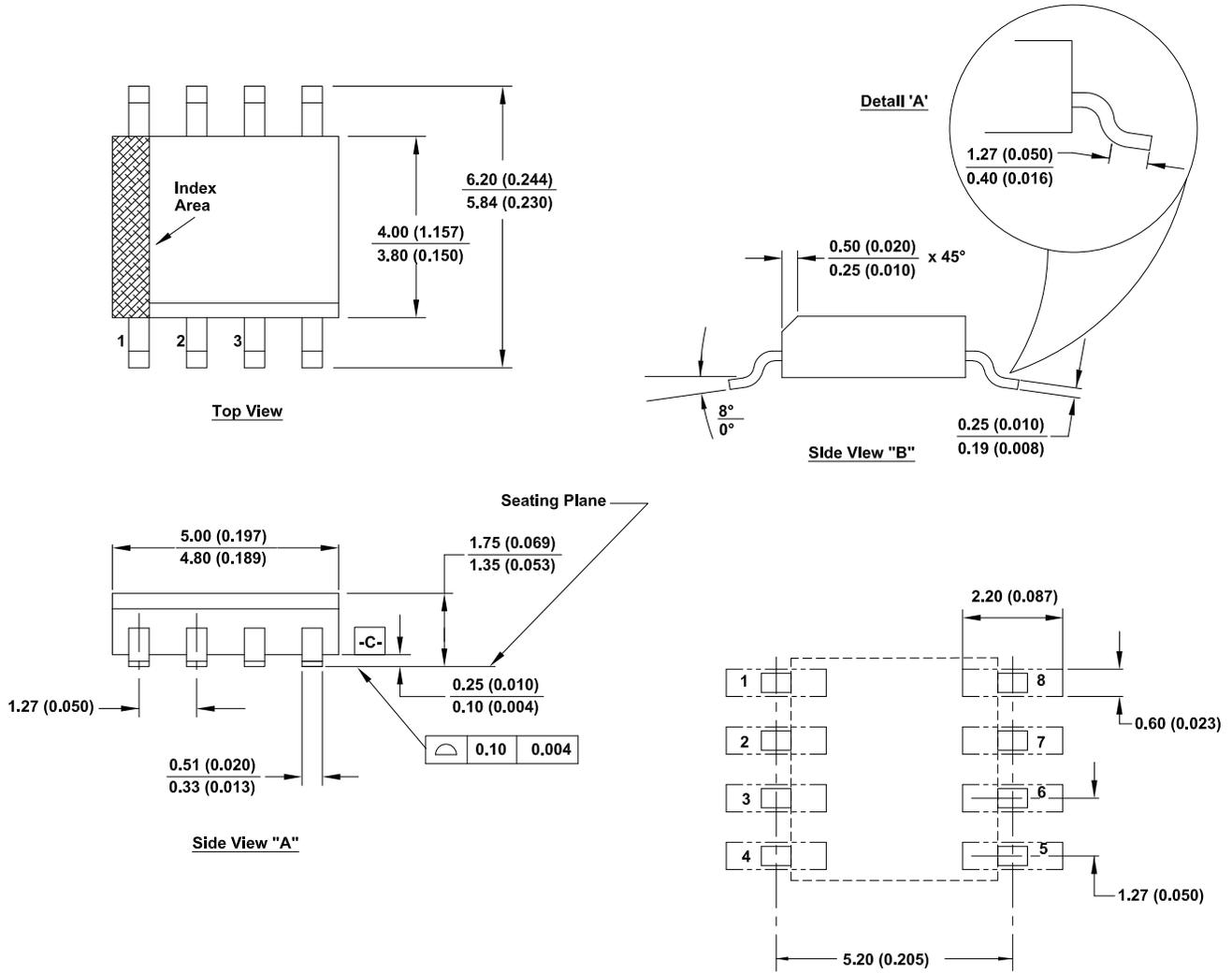


**NOTES:**

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-AA and AMSEY14.5m-1994.
3. Plastic or metal protrusions of 0.15mm max per side are not included.
4. Plastic interlead protrusions of 0.15mm max per side are not included.
5. Dimensions are measured at Datum Plane "H".
6. Dimensions in ( ) are for reference only.

For the most recent package outline drawing, see M8.15.

M8.15  
 8 Lead Narrow Body Small Outline Plastic Package  
 Rev 5, 4/2021

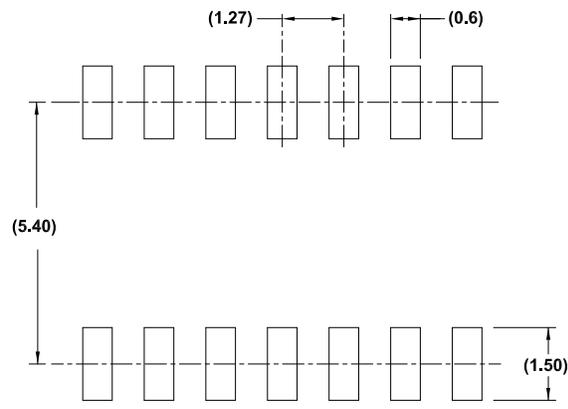
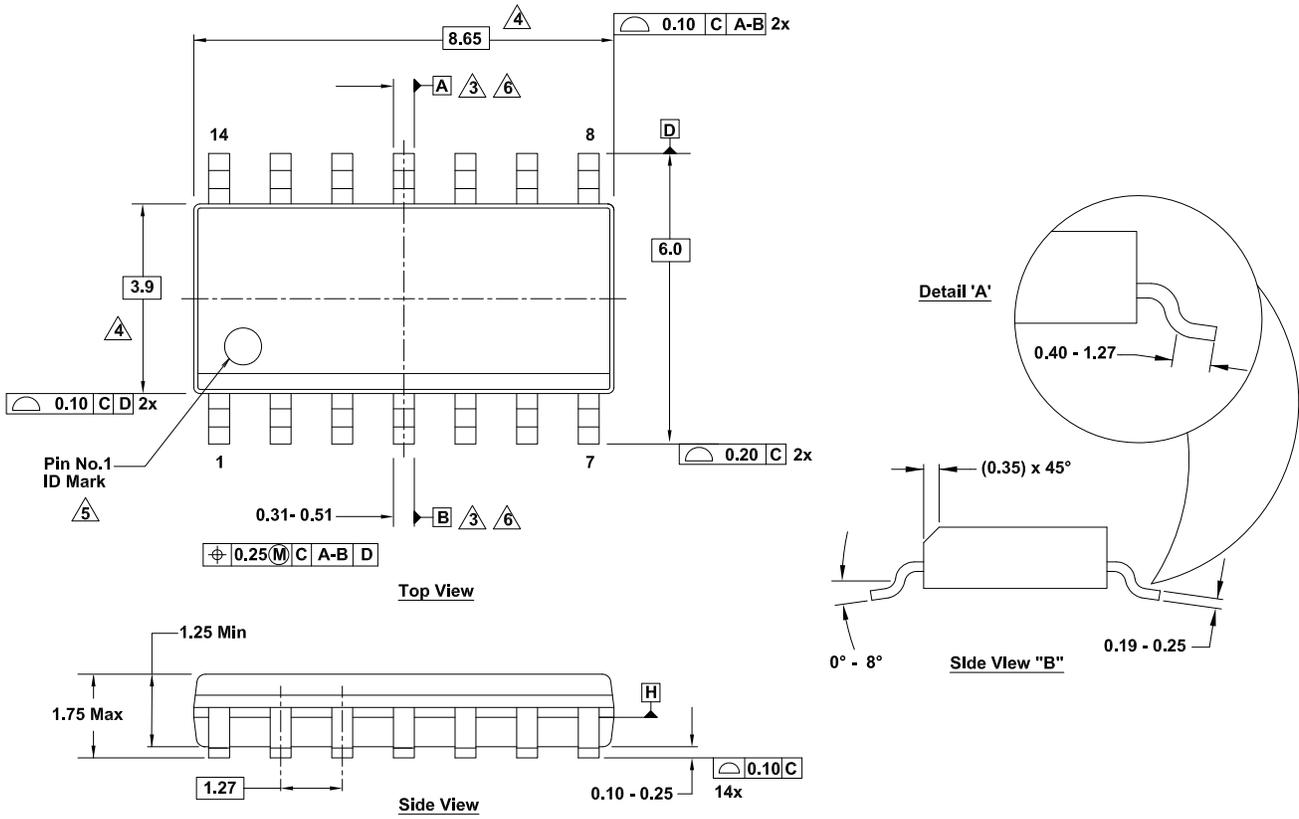


**NOTES:**

- 1 Dimensioning and tolerancing conform to AMSEY14.5m-1994.
- 2 Package length does not include mold flash, protrusion or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 Inch) per side.
- 3 Package width does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 4 The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 5 Terminal numbers are shown for reference only.
- 6 The lead width as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- 7 Controlling dimension: MILLIMETER. Converted inch dimension are not necessarily exact.
- 8 This outline conforms to JEDEC publication MS-012-AA ISSUE C.

For the most recent package outline drawing, see M14.15.

M14.15  
 14 Lead Narrow Body Small Outline Plastic Package  
 Rev 2, 6/20



Typical Recommended Land Pattern

- Notes:
1. Dimensions are in millimeters.  
 Dimensions in ( ) for reference only.
  2. Dimensioning and tolerancing conform to ASME Y14.5m-1994.
  3. Datums A and B are determined at Datum H.
  4. Dimension does not include interlead flash or protrusions.  
 Interlead flash or protrusions shall not exceed 0.25mm per side.
  5. The pin #1 identifier can be either a mold or mark feature.
  6. Does not include dambar protrusion. Allowable dambar protrusion shall be 0.10mm total in excess of lead width at maximum condition.
  7. Reference to JEDEC MS-012-AB.

## IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES (“RENESAS”) PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Rev.1.0 Mar 2020)

### Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,  
Koto-ku, Tokyo 135-0061, Japan  
[www.renesas.com](http://www.renesas.com)

### Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:  
[www.renesas.com/contact/](http://www.renesas.com/contact/)

### Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.